

### PNP -1.0A -30V Middle Power Transistor

Parameter	Value
$V_{CEO}$	-30V
I <sub>C</sub>	-1.0A

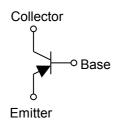
#### Features

- 1) Suitable for Middle Power Driver
- 2) Complementary NPN Types: 2SCR293P
- 3) Low V<sub>CE(sat)</sub>

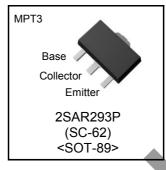
$$V_{CE(sat)} = -0.35V(Max.)$$
  
 $(I_C/I_B = -500mA/ -25mA)$ 

4) Lead Free/RoHS Compliant.

### •Inner circuit



#### Outline



# Applications

Motor driver , LED driver Power supply

## Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SAR293P	MPT3	4540	T100	180	12	1,000	ML

### ● Absolute maximum ratings (Ta = 25°C)

	Unit
_30	V
-30	V
<del>-6</del>	V
-1.0	А
-2.0	А
0.5	W
2.0	W
150	°C
−55 to +150	°C
)	-30 -6 -1.0 -2.0 0.5 2.0 150

<sup>\*1</sup> Pw=10ms, single pulse

<sup>\*2</sup> Each terminal mounted on a reference land

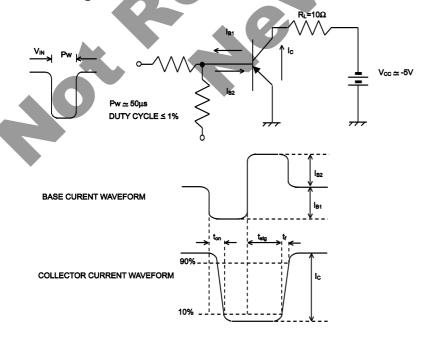
<sup>\*3</sup> Mounted on a ceramic board (40×40×0.7 mm)

### ●Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV <sub>CEO</sub>	I <sub>C</sub> = -1mA	-30	-	-	V
Collector-base breakdown voltage	BV <sub>CBO</sub>	$I_{C} = -10 \mu A$	-30	-	-	V
Emitter-base breakdown voltage	BV <sub>EBO</sub>	I <sub>E</sub> = -10μA	<del>-</del> 6	ı	-	V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = -30V	ı	-	-100	nA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = -6V	-	-	-100	nA
Collector-emitter saturation voltage	V <sub>CE(sat)</sub> *1	$I_C = -500 \text{mA}, I_B = -25 \text{mA}$		-0.15	-0.35	V
DC current gain	h <sub>FE</sub>	$V_{CE} = -2V, I_{C} = -100 \text{mA}$	270	-	680	-
Transition frequency	f <sub>T</sub>	$V_{CE} = -2V$ , $I_E = -100$ mA f=100MH <sub>Z</sub>	-	320	-	MHz
Output capacitance	C <sub>ob</sub>	$V_{CB} = -10V, I_{E} = 0A,$ f = 1MHz	-	7	-	pF
Turn-on time	t <sub>on</sub> *2	I <sub>C</sub> = -500mA		60	-	ns
Storage time	t <sub>stg</sub> *2	I <sub>B1</sub> = -25mA I <sub>B2</sub> =25mA	-	160	-	ns
Fall time	t <sub>f</sub> *2	V <sub>CC</sub> ≃ –5V	-	50	-	ns

<sup>\*1</sup> Pulsed

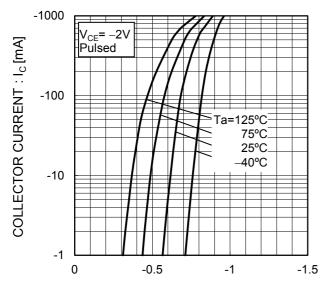
## •Switching time test circuit



<sup>\*2</sup> See switching time test circuit

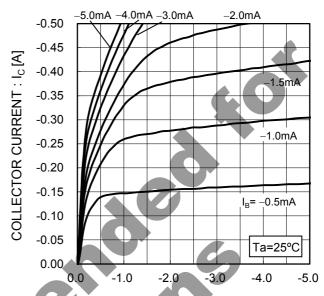
### ●Electrical characteristic curves(Ta = 25°C)

Fig.1 Ground Emitter Propagation Characteristics



BASE TO EMITTER VOLTAGE :  $V_{BE}[V]$ 

Fig.2 Typical Output Characteristics



COLECTOR TO EMITTE VOLTAGE : V<sub>CE</sub> [V]

Fig.3 DC Current Gain vs. Collector Current(I)

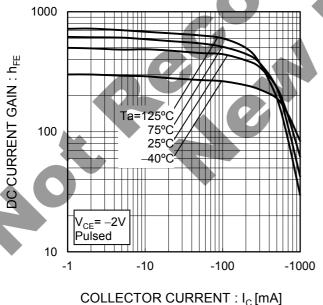
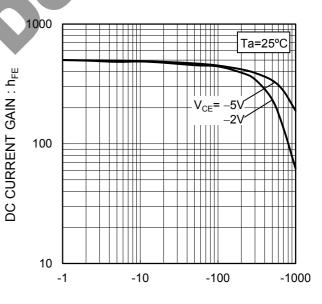


Fig.4 DC current gain vs. output current (II)

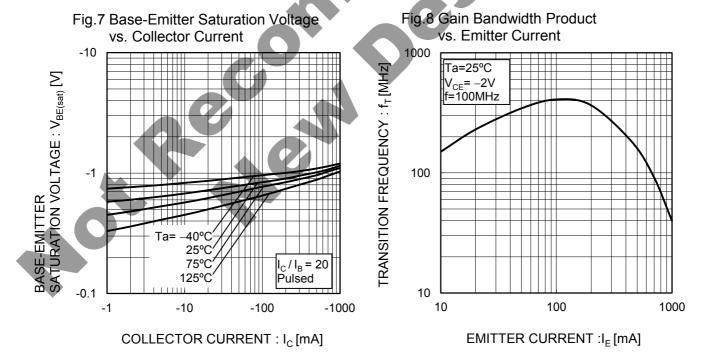


COLLECTOR CURRENT : I<sub>C</sub> [mA]

### ●Electrical characteristic curves(Ta = 25°C)

COLLECTOR CURRENT: Ic [mA]

Fig.6 Collector-Emitter Saturation Voltage Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (II) vs. Collector Current (I) -1 -10  $I_{\rm C} / I_{\rm B} = 20$ T<sub>a</sub>=25°C COLLECTOR-EMITTER SATURATION VOLTAGE : V<sub>CE(sat)</sub> [V] SATURATION VOLTAGE: V<sub>CE(sat)</sub> [V] Pulsed Pulsed -1 COLLECTOR-EMITTER -0.1 -0.1 a=125°C 75°C 25°C -40°C -0.01 -100 -10 -100 -1000 -1000 -1

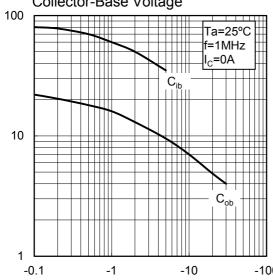


COLLECTOR CURRENT : I<sub>C</sub> [mA]

COLLECTOR OUTPUT CAPACITANCE: Cob [pF] EMITTER INPUT CAPACITANCE: Cib [pF]

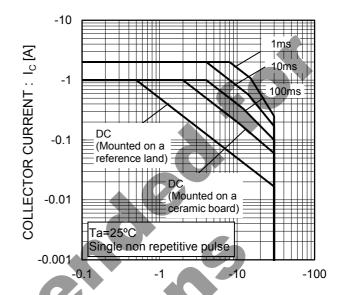
### ●Electrical characteristic curves(Ta = 25°C)

Fig.9 Emitter input capacitance vs.
Emitter-Base Voltage
Collector output capacitance vs.
Collector-Base Voltage



COLLECTOR - BASE VOLTAGE :  $V_{CB}$  [V] EMITTER - BASE VOLTAGE :  $V_{EB}$  [V]

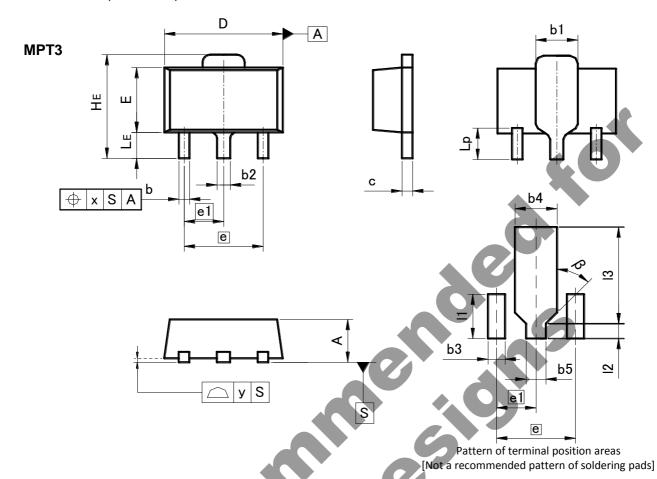
Fig.10 Safe Operating Area



COLLECTOR TO EMITTER VOLTAGE :  $V_{CE}\ [V]$ 



## ●Dimensions (Unit: mm)



DIM	MILIM	ETERS	INCHES		
DIIVI	MIN	MAX	MIN	MAX	
Α	1.40	1.50	0.055	0.059	
b	0.30	0.50	0.012	0.020	
b1	1.50	1.70	0.059	0.067	
b2	0.40	0.60	0.016	0.024	
C	0.35	0.50	0.014	0.020	
D	4.40	4.70	0.173	0.185	
E	2.40	2.70	0.094	0.106	
е	3.0	00	0.118		
e1	1.	50	0.059		
HE	3.70	4.30	0.146	0.169	
LE	0.80	1.20	0.031	0.047	
Lp	1.01	1.41	0.040	0.056	
Х		0.15	_	0.006	
У	_	0.10	_	0.004	

DIM	MILIMI	ETERS	INCHES		
	MIN	MAX	MIN	MAX	
b3	_	0.65	-	0.026	
b4	_	1.70	-	0.067	
b5	_	0.75	-	0.030	
11	_	1.71	1	0.067	
12	_	0.58	1	0.023	
13	_	3.72	_	0.146	
β	45°		45	0	

Dimension in mm / inches

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